OSRAM LE D P1MR Datasheet

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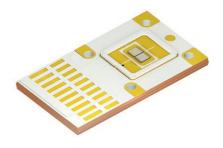




OSRAM OSTAR® Projection Power

LE D P1MR

OSRAM OSTAR Projection Power is a high luminance LED for projection applications.





Applications

- Projection & Display

- Visualization

Features

- Package: OSTAR High Power Projection
- Chip technology: UX:3
- Typ. Radiation: 120° (Lambertian emitter)
- Color: λ_{dom} = 440 nm (• deep blue)
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

Ordering Information

Total radiant flux ¹⁾ Ι _F = 8000 mA Φ _e	Ordering Code
18000 25900 mW	Q65113A1927
	I _F = 8000 mA Φ _e



Maximum Ratings

Parameter	Symbol		Values
Storage Temperature	T _{stg}	min.	-40 °C
	3	max.	85 °C
Junction Temperature	T _j	max.	150 °C
Forward Current	I _F	min.	200 mA
$T_{j} = T_{j,max}$	·	max.	13500 mA
Forward Current pulsed	F pulse		16000 mA
D = 0.7; f = 240 Hz; $T_j = T_{j,max}$			
Surge Current	I _{FS}	max.	19000 mA
$t_{p} \le 50 \ \mu s; D = 0.1; T_{j} = T_{j,max}$			
ESD withstand voltage	V _{ESD}		2 kV
acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	200		
Reverse current ²⁾	I _R	max.	200 mA
Max. voltage difference anode-board, cathode-board	$ \Delta V_{a-b} , \Delta V_{c-b} $	max.	40 V

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Characteristics

 T_{Board} = 25 °C; I_F = 8000 mA; f = 1000 Hz; D = 0.50

Parameter	Symbol		Values
Peak Wavelength	λ_{peak}	typ.	432 nm
Dominant Wavelength 3)	λ _{dom}	min.	435 nm
	uom	typ.	440 nm
		max.	445 nm
Spectral bandwidth at 50% I _{rel,max}	Δλ	typ.	18 nm
Viewing angle at 50% I_v	2φ	typ.	120 °
Radiating surface	A _{color}	typ.	3.35 x 1.55
			mm²
Partial Flux acc. CIE 127:2007 4)	$\Phi_{{\sf E}/{\sf V},\ {\sf 120}^\circ}$	typ.	0.77
I _F = 8000 mA	LIV, 120		
Forward Voltage ⁵⁾	V _F	min.	6.4 V
I _F = 8000 mA		typ.	6.8 V
		max.	7.6 V
Reverse voltage (ESD device)	V _{r esd}	min.	45 V
Reverse voltage ²⁾	V _R	max.	1.2 V
I _R = 20 mA	ι.		
Real thermal resistance junction/board	$R_{thJB real}$	typ.	0.90 K / W
Electrical thermal resistance junction/board	R _{thJB elec.}	typ.	0.54 K / W
with efficiency η_e = 40 %	0000		



Brightness Groups

Group	Total radiant flux ¹⁾ I _F = 8000 mA min. Φ _e	Total radiant flux ¹⁾ I _F = 8000 mA max. Φ _e
GP	18000 mW	 19400 mW
GQ	19400 mW	21000 mW
GR	21000 mW	22400 mW
GS	22400 mW	24000 mW
GT	24000 mW	25900 mW

Wavelength Groups

Group	Dominant Wavelength ³⁾	Dominant Wavelength ³⁾	
	min.	max.	
	λ_{dom}	λ_{dom}	
R	435 nm	445 nm	

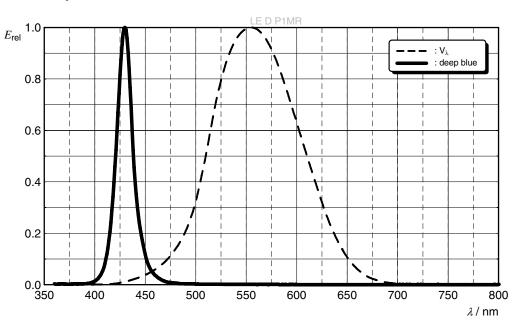
Group Name on Label

Brightness	Wavelength
GP	R



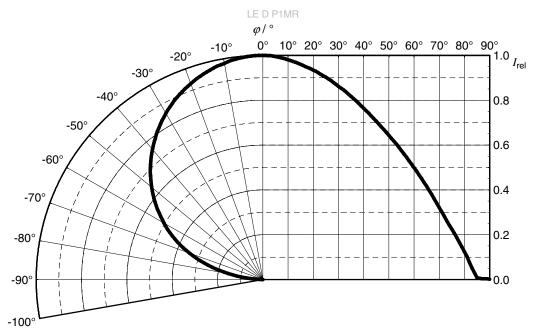
Relative Spectral Emission⁴⁾

 $E_{_{rel}} = f(\lambda); I_{_F} = 8000 \text{ mA}; T_{_J} = 25 \text{ }^{\circ}\text{C}$



Radiation Characteristics⁴⁾

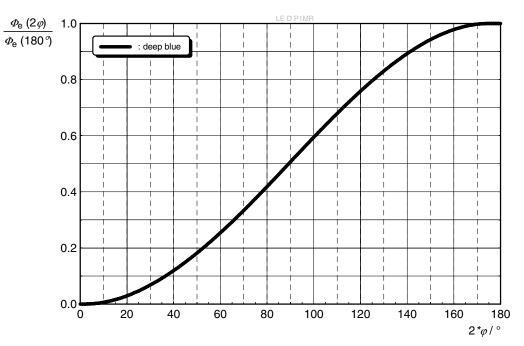
 $I_{rel} = f(\phi); T_J = 25 \ ^{\circ}C$





Relative Partial Flux⁴⁾

 $\Phi_{_{\rm E}}(2\phi)/\Phi_{_{\rm E}}(180^\circ) = f(\phi); T_{_{\rm J}} = 25 \ ^{\circ}{\rm C}$

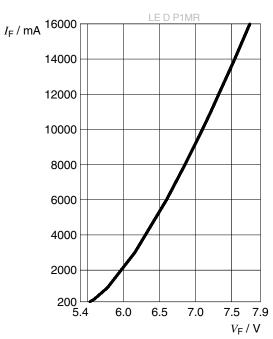


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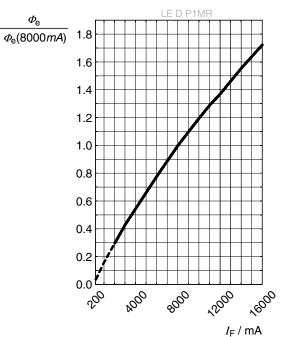
Forward current ⁴⁾

I_F = f(V_F); T_J = 25 °C



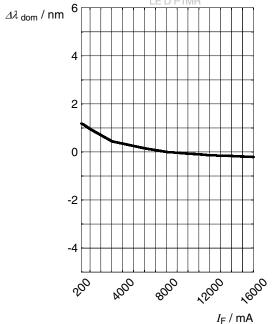
Relative Radiant Power^{4), 6)}

 $\Phi_{\rm E}/\Phi_{\rm E}(8000 \text{ mA}) = f(I_{\rm F}); T_{\rm J} = 25 \text{ °C}$



Dominant Wavelength ⁴⁾

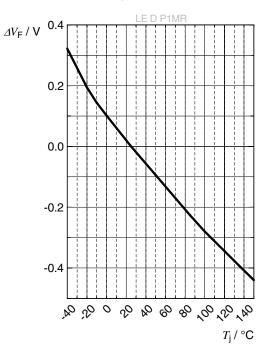
 $\Delta \lambda_{dom} = f(I_F); T_J = 25 \ ^{\circ}C$





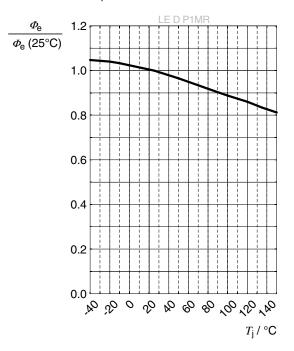
Forward Voltage ⁴⁾

 $\Delta V_{_{\rm F}} = V_{_{\rm F}} - V_{_{\rm F}}(25 \ ^{\circ}{\rm C}) = f(T_{_{\rm J}}); I_{_{\rm F}} = 8000 \text{ mA}$



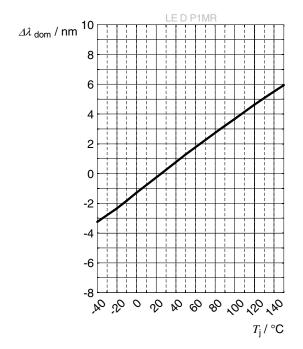
Relative Radiant Power⁴⁾

 $\Phi_{E}/\Phi_{E}(25 \text{ °C}) = f(T_{i}); I_{E} = 8000 \text{ mA}$



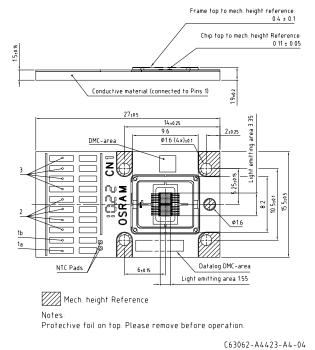
Dominant Wavelength ⁴⁾

 $\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \ ^{\circ}C) = f(T_j); I_F = 8000 \ mA$





Dimensional Drawing 7)



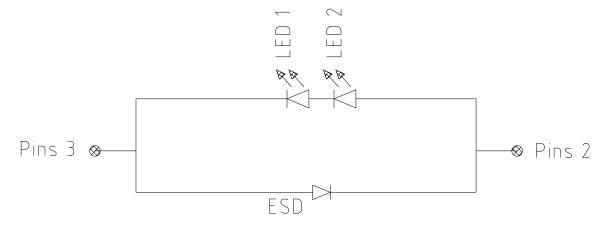
Further Information:

Approximate Weight:	5,000.0 mg
ESD advice:	The device is protected by ESD device which is connected in parallel to the Chip.
Notes:	For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for any kind of wet cleaning or ultrasonic cleaning.
Connector:	TYU, TU1502 Series, 1.50mm Pitch, Wire to Board Wafer, Part Number TU1502WNR-10S-*-*
Recommended mating connector:	TYU, TU1502 Series, 1.50mm Pitch, Wire to Board Housing, Part Number TU1502HNO-10 TYU, TU1502 Series, 1.50mm Pitch, Terminal, Part Number TU1502TPO-*





Electrical Internal Circuit



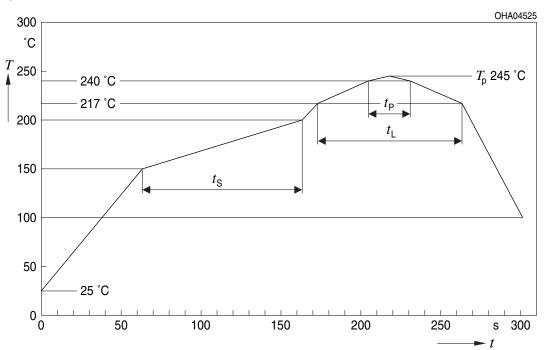
Pins 1a: NTC/Substrate potential, isolated from Cathode and Anode Pins 1b: NTC Pins 2: Anode

Pins 3: Cathode



Reflow Soldering Profile





Profile Feature	Symbol Pb-		o-Free (SnAgCu) Assembly		Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat [•]) 25 °C to 150 °C			2	3	K/s
Time t _s T _{Smin} to T _{Smax}	t _s	60	100	120	S
Ramp-up rate to peak ^{*)} T_{smax} to T_{p}			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	Τ _Ρ		245	260	°C
Time within 5 °C of the specified peak temperature T_{p} - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

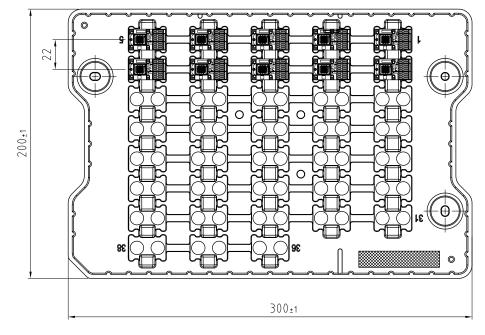
 * slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

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Tray 7)

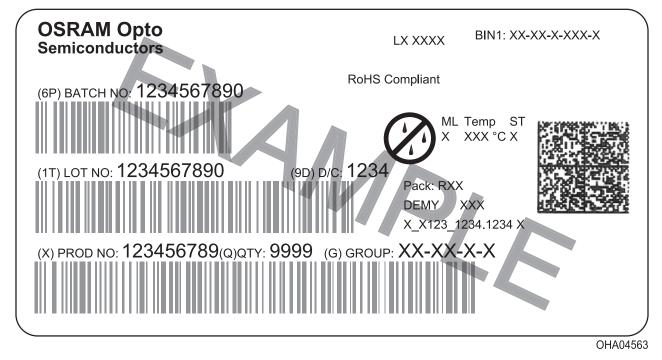
38 pieces per tray



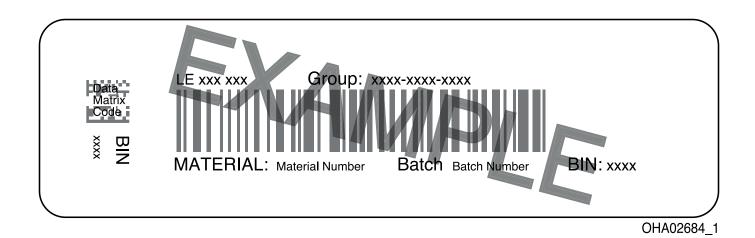
C63062-A4389-B10-01



Barcode-Product-Label (BPL)

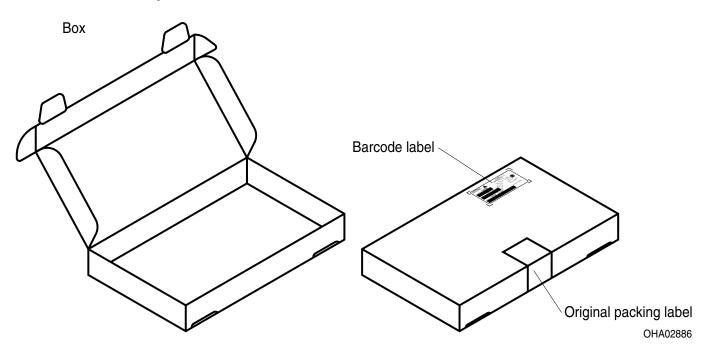


Barcode-Tray-Label (BTL)



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Schematic Transportation Box 7)



Dimensions of Transportation Box

Width	Length	Height	
333 ± 5 mm	218 ±5 mm	28 ± 5 mm	
337 ± 5 mm	218 ±5 mm	63 ± 5 mm	



Data Matrix Code Description

The Data Matrix Code bin information is Laser marked during testing Content: aaaa@bbbbb@cccc@ddddd@eeeee Data Matrix Code Type: ECC200

- a = Luminous Flux (Phiv) [Im] or Radiant Flux (Phie) [W]
- b = Forward Voltage (Vf) [V] c = Wavelength (Ldom) [nm]
- d = Color Coordinate Cx
- e = Color Coordinate Cy
- @: Seperator = Blank

- (example: 3306) (example: 3.46)
- (example: 618)
- (example: 0.321)
- (example: 0.641)



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- ¹⁾ Brightness: Brightness values are measured during a pulse train of 100 ms with a pulse width of 500 µs and a frequencey of 1 kHz, with an internal reproducibility of +/- 8 % and an expanded uncertainty of +/- 11 % (acc. to GUM with a coverage factor of k = 3). The peak brightness is calculated according to the pulse duration and frequency.
- ²⁾ Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- ³⁾ Wavelength: The wavelength is measured during a pulse train of 100 ms with a pulse width of 500 μ s and a frequencey of 1 kHz, with an internal reproducibility of ± 0,5 nm and an expanded uncertainty of ± 1 nm (acc. to GUM with a coverage factor of k=3).
- ⁴⁾ Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁵⁾ **Forward Voltage:** The forward voltage is measured during a pulse of typical 500 μs, with an internal reproducibility of +/- 0,05 V and an expanded uncertainty of +/- 0,1 V (acc. to GUM with a coverage factor of k=3).
- ⁶⁾ **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- ⁷⁾ **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



Revision History

Version	Date	Change
1.0	2021-05-31	Initial Version
1.1	2022-08-17	Dimensional Drawing



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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